



PSCIA SERIES DIE

P-Channel JFETs

T-37-25

The PSCIA Series is a p-channel JFET analog switch designed to complement our n-channel NCB Series. They feature low on-resistance and good off-isolation as well as the fast switching associated with JFETs. Die are supplied with 100% visual sort to the criteria of MIL-STD-750C, Method 2072.

PSCIA1CHP*	PSCIA2CHP*	PSCIA3CHP*	PSCIA4CHP*
2N5114 J174 SST174	2N5115 J175 SST175	2N5116 J176 SST176	J177 SST177
*Meets or exceeds specification for all part numbers listed below			

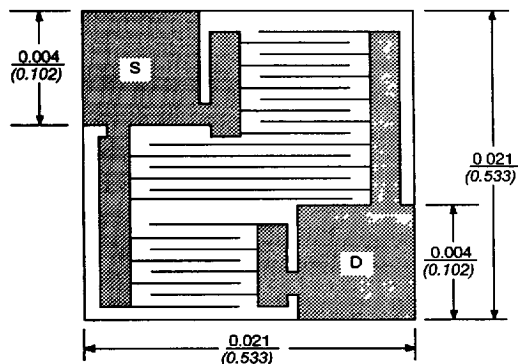
For additional design information please consult the typical performance curves PSCIA.

DESIGNED FOR:

- Analog Switches
- Commutators
- Choppers
- Integrator Reset Switch

FEATURES

- Low Insertion Loss in Switching Systems
 $r_{DS(ON)} < 75 \Omega$ (2N5114)
- Short Sample and Hold Aperture Time
 $C_{rss} < 7$ pF
- High Off-Isolation $I_{D(OFF)} < 500$ pA



Gate backside contact
Nominal Thickness
0.009 inches
0.228 mm

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ Unless Otherwise Noted)

PARAMETERS/TEST CONDITIONS	SYMBOL	LIMITS	UNITS
Gate-Drain Voltage	V_{GD}	30	V
Gate-Source Voltage	V_{GS}	30	
Gate Current	I_G	50	mA
Operating and Storage Temperature Range	T_J, T_{stg}	-55 to 150	$^\circ\text{C}$

PSCIA SERIES DIE



SPECIFICATIONS ^a				LIMITS				
PARAMETER	SYMBOL	TEST CONDITIONS	TYP ^b	PSCIA1CHP		PSCIA2CHP		UNIT
				MIN	MAX	MIN	MAX	
STATIC								
Gate-Source Breakdown Voltage	$V_{(BR)GSS}$	$I_G = 1 \mu A, V_{DS} = 0 V$	45	30		30		V
Gate-Source Cutoff Voltage	$V_{GS(OFF)}$	$V_{DS} = -15 V, I_D = -1 nA$		5	10	3	6	
Saturation Drain Current ^c	I_{DSS}	$V_{GS} = 0 V$		-30	-90			mA
Gate Reverse Current	I_{GSS}	$V_{GS} = -20 V, V_{DS} = 0 V$	5			-15	-60	pA
		$T_A = 150^\circ C$	0.01					μA
Gate Operating Current	I_G	$V_{DG} = -15 V, I_D = -1 mA$	-5					pA
Drain Cutoff Current	$I_{D(OFF)}$	$V_{DS} = -15 V, V_{GS} > V_{GS(OFF)}$	-10					nA
		$T_A = 150^\circ C$	-0.02					
Drain-Source On-Resistance	$r_{DS(ON)}$	$V_{GS} = 0 V, I_D = -1 mA$			75		100	Ω
Gate-Source Forward Voltage	$V_{GS(F)}$	$I_G = -1 mA, V_{DS} = 0 V$	-0.7					V
DYNAMIC								
Common-Source Forward Transconductance	g_{fs}	$V_{DG} = -15 V, I_D = -1 mA$	4.5					mS
Common-Source Output Conductance	g_{os}	$f = 1 kHz$	20					μS
Drain-Source On-Resistance	$r_{ds(ON)}$	$V_{GS} = 0 V, I_D = 0 V, f = 1 kHz$			75		100	Ω
Common-Source Input Capacitance	C_{iss}	$V_{DS} = -15 V, V_{GS} = 0 V$	20					pF
Common-Source Reverse Transfer Capacitance	C_{rss}	$V_{DS} = 0 V, V_{GS} > V_{GS(OFF)}$	5					
		$f = 1 MHz$						
Equivalent Input Noise Voltage	\bar{e}_n	$V_{DG} = -10 V, I_D = -1 mA$	20					nV/\sqrt{Hz}
		$f = 1 kHz$						
SWITCHING								
Turn-On Time	$t_{d(ON)}$	$V_{GS(ON)} = 0 V$	6					ns
	t_r	P/N $V_{GS} V_{GS(OFF)} R_L$	10					
Turn-Off Time	$t_{d(OFF)}$	PSCIA1 -10V -15mA 20V 130 Ω	6					
	t_f	PSCIA2 -8V -7mA 12V 800 Ω	15					

NOTES:

- a. $T_A = 25^\circ C$ unless otherwise noted.
 b. For design aid only, not subject to production testing.
 c. Pulse test; PW = 300 μS , duty cycle $\leq 2\%$.



PSCIA SERIES DIE

SPECIFICATIONS ^a				LIMITS				
PARAMETER	SYMBOL	TEST CONDITIONS	TYP ^b	PSCIA3CHP		PSCIA4CHP		UNIT
				MIN	MAX	MIN	MAX	
STATIC								
Gate-Source Breakdown Voltage	$V_{(BR)GSS}$	$I_G = 1 \mu A, V_{DS} = 0 V$	45	30		30		V
Gate-Source Cutoff Voltage	$V_{GS(OFF)}$	$V_{DS} = -15 V, I_D = -10 nA$		1	4	0.3	2.25	
Saturation Drain Current ^c	I_{DSS}	$V_{GS} = 0 V$		$V_{DS} = -18 V$				mA
				$V_{DS} = -15 V$	-5	-25	-1.5	
Gate Reverse Current	I_{GSS}	$V_{GS} = -20 V, V_{DS} = 0 V$			5			pA
				$T_A = 150^\circ C$	0.01			μA
Gate Operating Current	I_G	$V_{DG} = -15 V, I_D = -1 mA$	-5					pA
Drain Cutoff Current	$I_{D(OFF)}$	$V_{DS} = -15 V, V_{GS} > V_{GS(OFF)}$			-10			nA
				$T_A = 150^\circ C$	-0.02			
Drain-Source On-Resistance	$r_{DS(ON)}$	$V_{GS} = 0 V, I_D = -1 mA$			150		300	Ω
Gate-Source Forward Voltage	$V_{GS(F)}$	$I_G = -1 mA, V_{DS} = 0 V$	-0.7					V
DYNAMIC								
Common-Source Forward Transconductance	g_{fs}	$V_{DG} = -15 V, I_D = -1 mA$ $f = 1 kHz$	4.5					mS
Common-Source Output Conductance	g_{os}		20					μS
Drain-Source On-Resistance	$r_{ds(ON)}$	$V_{GS} = 0 V, I_D = 0 V, f = 1 kHz$			175		300	Ω
Common-Source Input Capacitance	C_{iss}	$V_{DS} = -15 V, V_{GS} = 0 V$ $f = 1 MHz$	20					pF
Common-Source Reverse Transfer Capacitance	C_{rss}	$V_{DS} = 0 V, V_{GS} > V_{GS(OFF)}$ $f = 1 MHz$	5					
Equivalent Input Noise Voltage	\bar{e}_n	$V_{DG} = -10 V, I_D = -1 mA$ $f = 1 kHz$	20					nV/\sqrt{Hz}
SWITCHING								
Turn-On Time	$t_{d(ON)}$	$V_{GS(ON)} = 0 V$ P/N $V_{DD} \quad t_{D(ON)} \quad V_{GS(ON)} \quad R_L$ PSCIA3 -8V -3mA 8V 2000 Ω PSCIA4 -6V -3mA 8V 2000 Ω	6					ns
	t_r		10					
Turn-Off Time	$t_{d(OFF)}$		6					ns
	t_f		15					

NOTES:

- a. $T_A = 25^\circ C$ unless otherwise noted.
- b. For design aid only, not subject to production testing.
- c. Pulse test; PW = 300 μS , duty cycle $\leq 2\%$.